

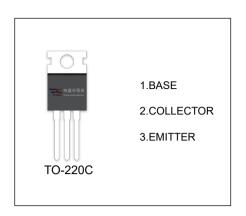
KTC3229 TRANSISTOR (NPN)

FEATURES

- High Breakdown Voltage
- Small Collector Output Capacitance

APPLICATIONS

Color TV Chroma Output Applications



MAXIMUM RATINGS (T_a =25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	300	V
V _{CEO}	Collector-Emitter Voltage	300	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current	0.1	Α
Pc	Collector Power Dissipation	2	W
R _{0JA}	Thermal Resistance From Junction To Ambient	63	°C/W
T _j ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	℃

ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA,I _E =0	300			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =1mA,I _B =0	300			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =100μA,I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =240V,I _E =0			1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =5V,I _C =0			1	μA
DC current gain	h _{FE(1)}	V _{CE} =10V, I _C =20mA	30		200	
DC current gain	h _{FE(2)}	V _{CE} =10V, I _C =0.5mA	20			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =10mA,I _B =1mA			1	V
Collector output capacitance	Cob	V _{CB} =20V,I _E =0, f=1MHz			4	pF
Transition frequency	f _T	Vce=20V,Ic=20mA	75			MHz